



Sheet 1 of 3

PTO-1449 (Modified)		ATTY. DOCKET NO. P043D2C2C	SERIAL NUMBER 09/252,997
U.S. DEPARTMENT OF COMMERCE PATENT AND TRADEMARK OFFICE		APPLICANT(S) FARMWALD ET AL.	
INFORMATION DISCLOSURE STATEMENT BY APPLICANT		FILING DATE FEBRUARY 19, 1999	GROUP ART UNIT NOT ASSIGNED

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EXAMINER INITIALS	DOCUMENT NUMBER	DATE	NAME	CLASS	SUB CLASS	FILING DATE
TNT	4,445,204	04/24/84	Nishiguchi	365	1911	
	4,821,226	04/11/89	Christopher et al.	365	RECEIVED 1995	
	4,882,712	11/21/89	Ohno et. al.	JUN 365	206 1999	
	4,951,251	08/21/90	Yamaguchi et al.	TECHNOLOGY CENTER 365	189-02	
	4,928,265	12/29/92 3 90	Beighe et al.	365	TER 2800 109-09	
	5,107,465	04/21/92	Fung et al.	365	232-08	
	5,206,833	04/27/93	Lee	365	233	
TNT	4,953,128	08/28/90	Kawai et al.	365	1911	

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OTHER DOCUMENTS (Including Author, Title, Date, Pertinent Pages, Etc.)

TNT	T.L. Jeremiah et. al., "SYNCHRONOUS PACKET SWITCHING MEMORY AND I/O CHANNEL," IBM Tech. Disc. Bul., Vol. 24, No. 10, pp. 4986-4987 (Mar. 1982)
TNT	L. R. Metzger, "A 16K CMOS PROM with Polysilicon Fusible Links", IEEE Journal of Solid State Circuits, vol. 18 No. 5, pp. 562-567 (Oct. 1983)
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TNT	D.T. Wong et. al., "An 11-ns 8Kx18 CMOS Static RAM with 0.5-µm Devices", IEEE Journal of Solid State Circuits, vol. 23 No. 5, pp. 1095-1103 (Oct. 1988)
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	5,018,111	05/21/91	Madland	365	233	
	4,734,880	03/29/88	Collins	711	105	
	4,183,095	01/08/80	Ward	365	189-02	
	4,975,872	12/04/90	Zaiki	365	49	
	5,016,226	05/14/91	Hiwada et al.	365	233	
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TNT	D. Jones, "Synchronous static ram", Electronics and Wireless World, vol.93, no.1622, pp. 1243-4 (Dec. 87)
TNT	F. Miller et. al., "HIGH FREQUENCY SYSTEM OPERATION USING SYNCHRONOUS SRAMS", Midcon/87 Conference Record, pp. 430-432 Chicago, IL, USA; 15-17 Sept. 1987
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TNT	F. Towler et. al., "A 128k 6.5ns Access/ 5ns Cycle CMOS ECL Static RAM", 1989 IEEE international Solid State Circuits Conference, (Feb. 1989)
TNT	M. Kimoto, "A 1.4ns/64kb RAM with 85ps/3680 Logic Gate Array", 1989 IEEE Custom Integrated Circuits Conference

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TNT	4,807,189	02/21/89	Pinkham et al.	365	189.05	
	4,092,665	05/30/78	Saran	341	63	
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	5,148,523	09/15/92	Harlin et al.	365	164	
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	4,788,667	05/22/90	Higuchi	365	193	
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TNT	M. Bazes et. al., "A Programmable NMOS DRAM Controller for Microcomputer Systems with Dual-Port Memory and Error Checking and Correction", IEEE Journal of Solid State Circuits, vol. 18 No. 2, pp. 164-172 (Apr. 1983)
TNT	R. Schmidt, "A memory Control Chip for Formatting Data into Blocks Suitable for Video Applications", IEEE Transactions on Circuits and Systems, vol. 36, No. 10 (Oct. 1989)
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TNT	T.C. Poon et. al., "A CMOS DRAM-Controller Chip Implementation", IEEE Journal of Solid State Circuits, vol. 22 No. 3, pp. 491-494 (June 1987)
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